

Small Package, High Performance, Asyn-Boost Converter for 6 White LEDs

General Description

The RT9292 is a high frequency and high efficiency asynchronous boost converter for WLED driving application. It integrates a 28V MOSFET to support up to 6 White LEDs for panel backlighting and OLED power applications. Besides, an internal soft start function is integrated to reduce the inrush current. Moreover, the device operates with 1MHz fixed switching frequency for the use of small external components and better EMI performance. For lower voltage application, the IC provides a 26V over voltage protection function for using the low-cost and small output capacitors. The LED current is initially set by the external sense resistor (R_{SET}), and the feedback voltage for the RT9292 series will be 104mV and 330mV respectively. The RT9292 is available in TSOT-23-6 and WDFN-8L 2x2 tiny packages to achieve best solution for PCB space and total BOM cost saving considerations.

Ordering Information

RT9292	□□□
	Package Type
	J6 : TSOT-23-6
	QW : WDFN-8L 2x2 (W-Type)
	Lead Plating System
	G : Green (Halogen Free and Pb Free)
	Feedback Reference Voltage
	B : 104mV
	D : 330mV

Note :

Richtek products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

For marking information, contact our sales representative directly or through a Richtek distributor located in your area.

Features

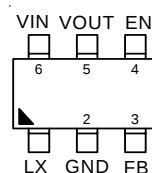
- V_{IN} Operating Range : 2.5V to 5.5V
- 28V Internal Power N-MOSFET Switch
- Wide Range PWM Dimming (200Hz to 200kHz)
- Minimize the External Component Counts
- Internal Soft Start
- Internal Compensation
- Under Voltage Protection
- Over Voltage Protection
- Over Temperature Protection
- Internal Schottky Diode
- Small TSOT-23-6 and 8-Lead WDFN Packages
- RoHS Compliant and Halogen Free

Applications

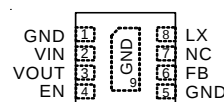
- Cellular Phones
- Digital Cameras
- PDAs and Smart Phones and MP3 and OLED.
- Portable Instruments

Pin Configurations

(TOP VIEW)

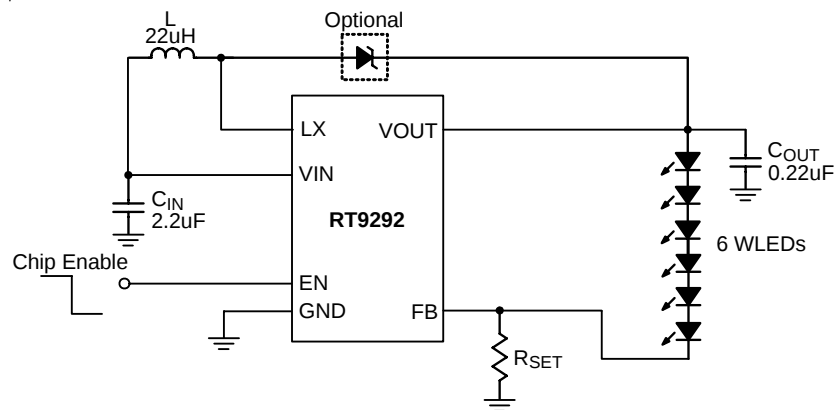


TSOT-23-6



WDFN-8L 2x2

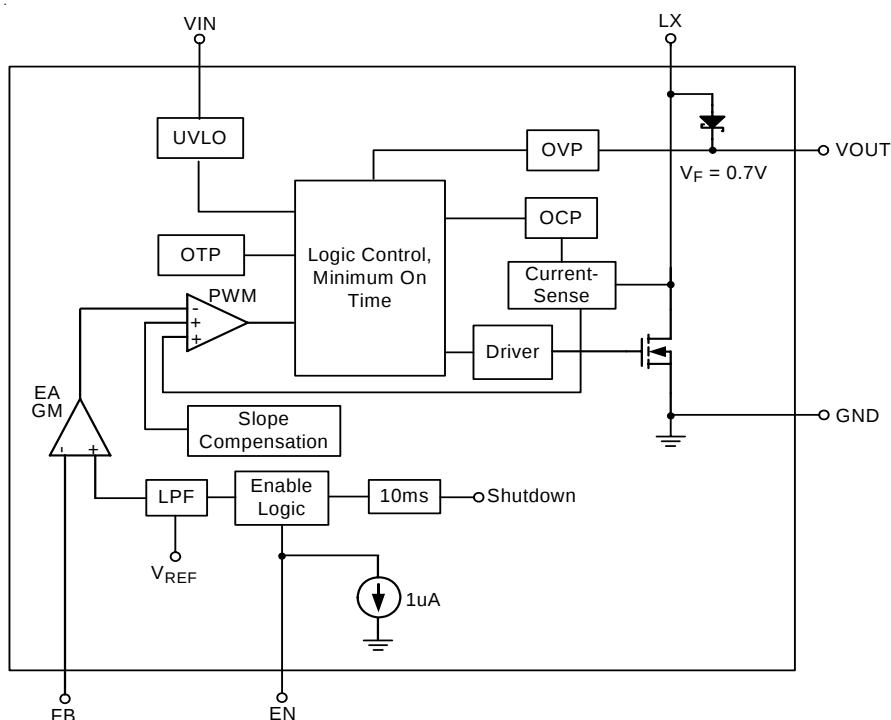
Typical Application Circuit



Functional Pin Description

Pin No.		Pin Name	Pin Function
RT9292□GJ6	RT9292□GQW		
1	8	LX	Switching Pin.
2	1, 5, 9 (Exposed pad)	GND	Ground Pin. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.
3	6	FB	Feed Back Pin, put a resistor to GND to set the current.
4	4	EN	Chip Enable (Active High).
5	3	VOUT	Output Voltage Pin.
6	2	VIN	Input Supply.
--	7	NC	No Internal Connection, keep floating.

Function Block Diagram



Absolute Maximum Ratings (Note 1)

• Supply Input Voltage, V_{IN} -----	–0.3V to 6V
• LX, VOUT Pins -----	–0.3V to 28V
• Other Pins -----	–0.3V to 6V
• Power Dissipation, P_D @ $T_A = 25^\circ\text{C}$	
TSOT-23-6 -----	0.392W
WDFN-8L 2x2 -----	0.606W
• Package Thermal Resistance (Note 2)	
TSOT-23-6, θ_{JA} -----	255°C/W
WDFN-8L 2x2, θ_{JA} -----	165°C/W
• Lead Temperature (Soldering, 10 sec.) -----	260°C
• Junction Temperature -----	150°C
• Storage Temperature Range -----	–65°C to 150°C
• ESD Susceptibility (Note 3)	
HBM (Human Body Mode) -----	2kV
MM (Machine Mode) -----	200V

Recommended Operating Conditions (Note 4)

• Junction Temperature Range -----	–40°C to 125°C
• Ambient Temperature Range -----	–40°C to 85°C

Electrical Characteristics

($V_{IN} = 3.7\text{V}$, $C_{IN} = 2.2\mu\text{F}$, $C_{OUT} = 0.22\mu\text{F}$, $I_{OUT} = 20\text{mA}$, $L = 22\mu\text{H}$, $T_A = 25^\circ\text{C}$, unless otherwise specified)

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage		V_{IN}		2.5	--	5.5	V
Under Voltage Lock Out		V_{UVLO}		2.0	2.2	2.4	V
UVLO Hysteresis				--	0.1	--	V
Quiescent Current		I_Q	FB = 1.5V, No Switching	--	400	600	μA
Supply Current		I_{IN}	FB = 0V, Switching	--		2	mA
Shutdown Current		I_{SHDN}	$V_{EN} < 0.4\text{V}$	--	1	4	μA
Line Regulation			$V_{IN} = 3.0$ to 4.3V	--	1	--	%
Load Regulation			1mA to 20mA	--	1	--	%
Operation Frequency		f_{OSC}		0.75	1.0	1.25	MHz
Maximum Duty Cycle				90	92	--	%
Feedback Reference Voltage	RT9292B	V_{REF}		94	104	114	mV
	RT9292D			313	330	347	
On Resistance		$R_{DS(ON)}$		--	0.5	1.0	Ω
EN Threshold	Logic-High Voltage	V_{IH}		1.4	--	--	V
	Logic-Low Voltage	V_{IL}		--	--	0.5	

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
EN Sink Current	I_{IH}		--	1	--	μA
EN Low Time to Shutdown	T_{SHDN}		--	10	--	ms
Dimming Frequency			0.2	--	200	kHz
Over-Voltage Threshold	V_{OVP}		25	26	28	V
Over-Voltage Hysteresis			--	1	--	V
Over-Current Threshold	I_{OCP}		500	700	--	mA
OTP	T_{OTP}		--	160	--	$^{\circ}C$
OTP Hysteresis			--	30	--	$^{\circ}C$
Schottky Forward Voltage	V_F	$I_{Diode} = 100mA$	--	0.7	--	V

Note 1. Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

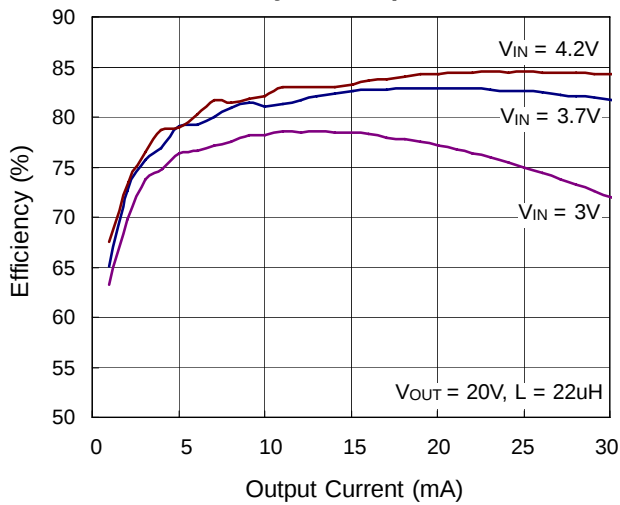
Note 2. θ_{JA} is measured in the natural convection at $T_A = 25^{\circ}C$ on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

Note 3. Devices are ESD sensitive. Handling precaution is recommended.

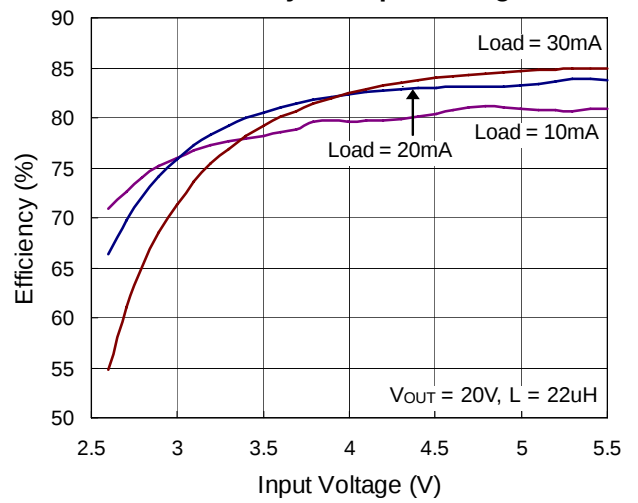
Note 4. The device is not guaranteed to function outside its operating conditions.

Typical Operating Characteristics

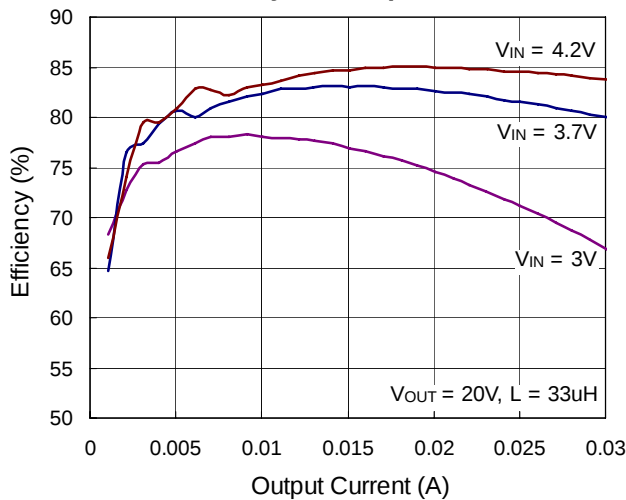
Efficiency vs. Output Current



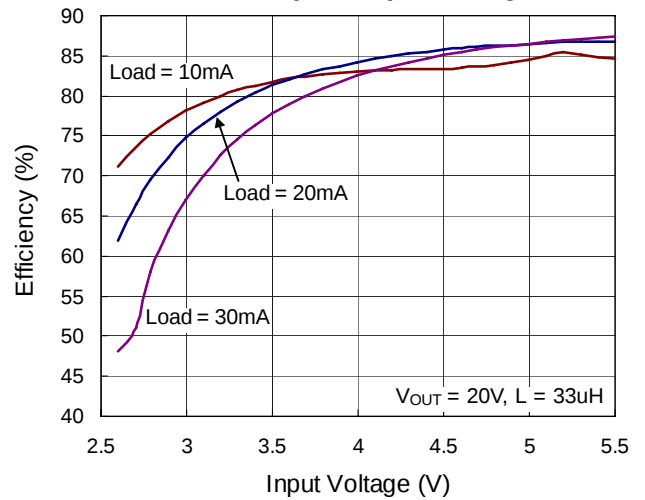
Efficiency vs. Input Voltage



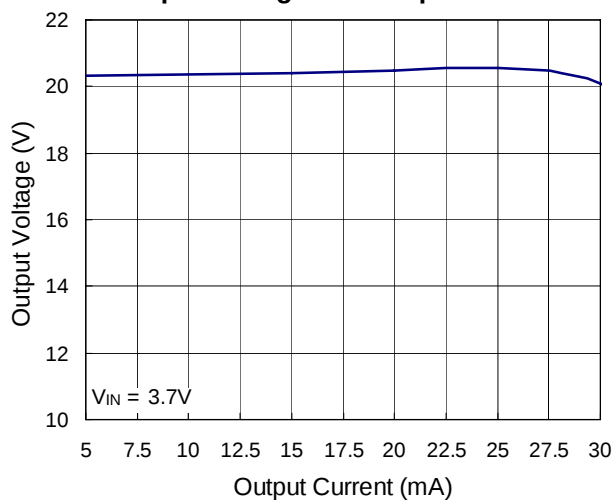
Efficiency vs. Output Current



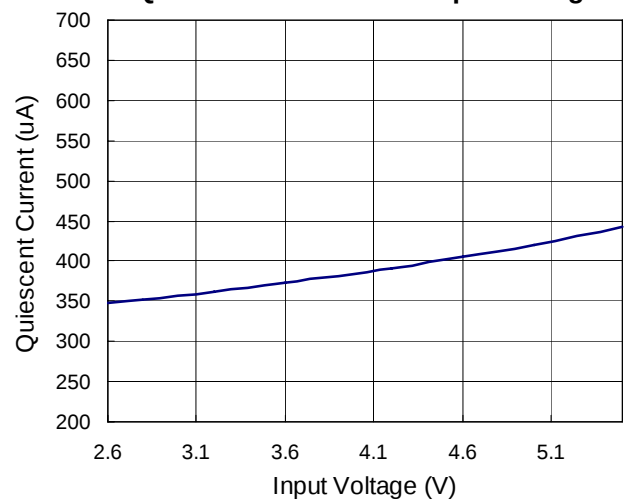
Efficiency vs. Input Voltage



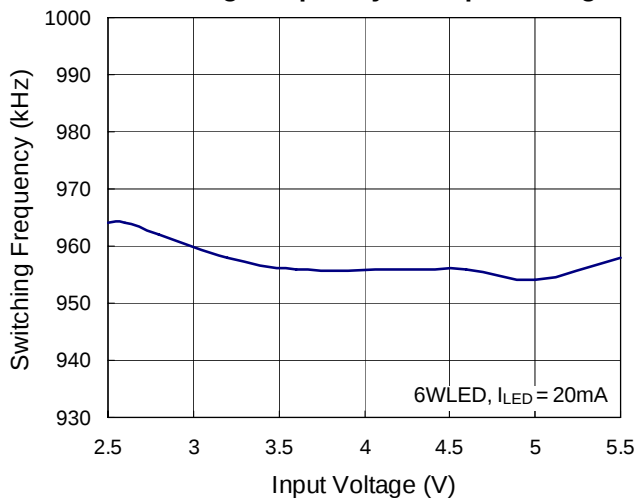
Output Voltage vs. Output Current



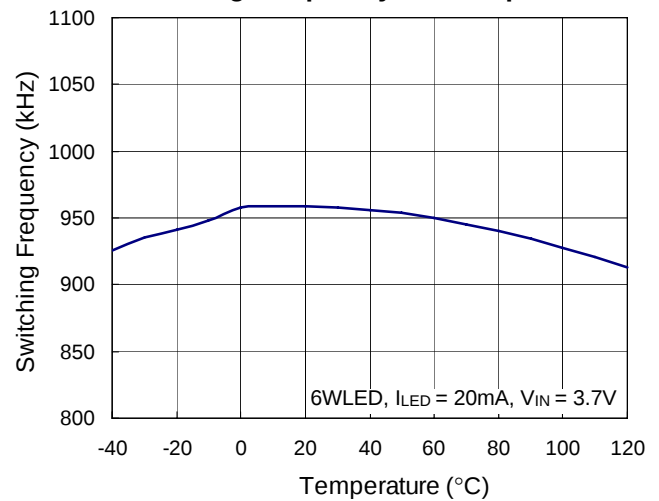
Quiescent Current vs. Input Voltage



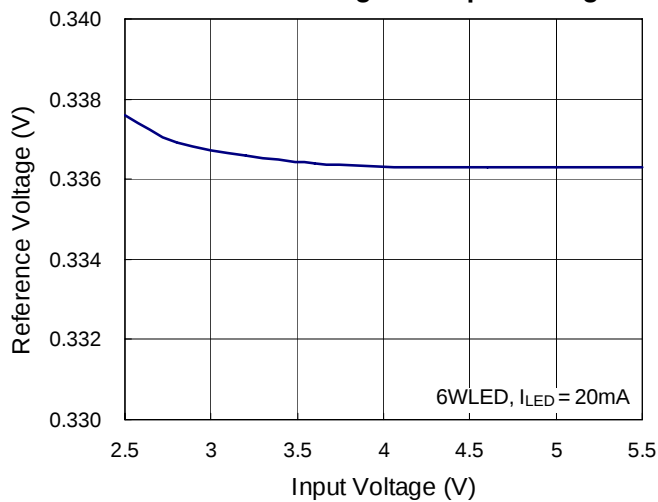
Switching Frequency vs. Input Voltage



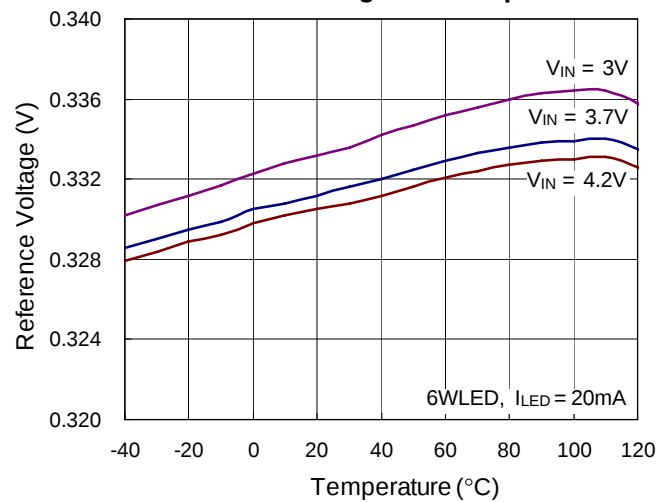
Switching Frequency vs. Temperature



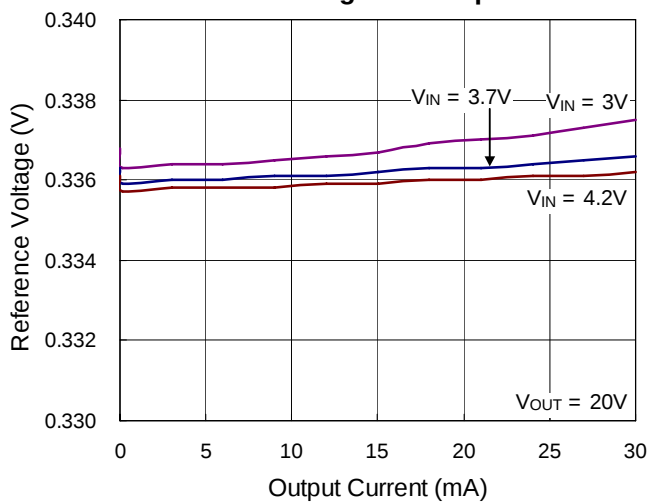
Reference Voltage vs. Input Voltage



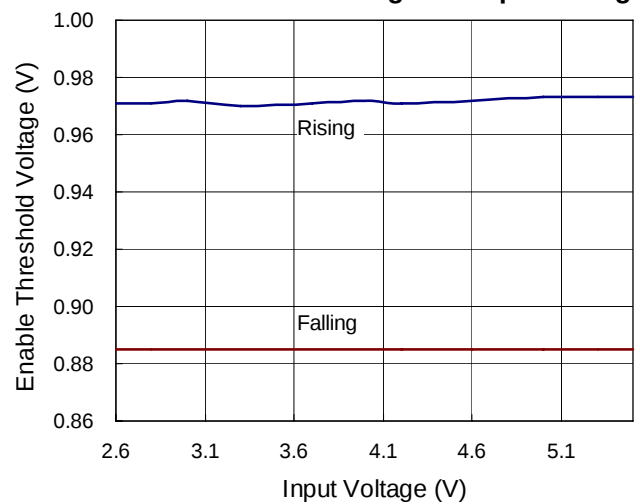
Reference Voltage vs. Temperature



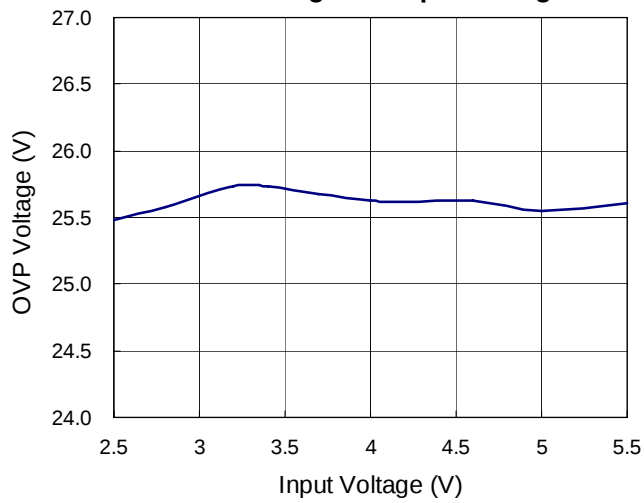
Reference Voltage vs. Output Current



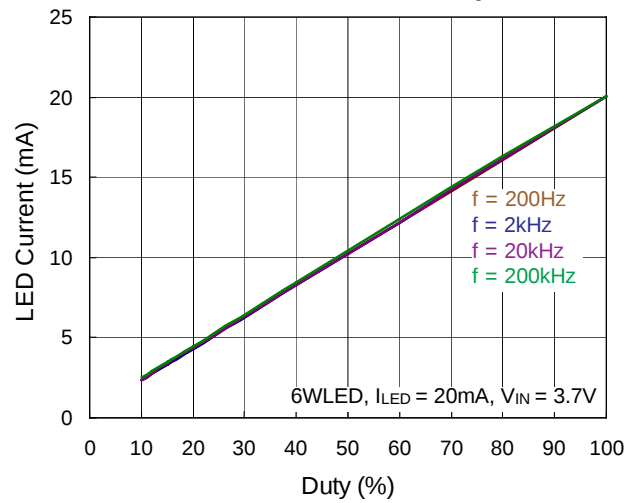
Enable Threshold Voltage vs. Input Voltage



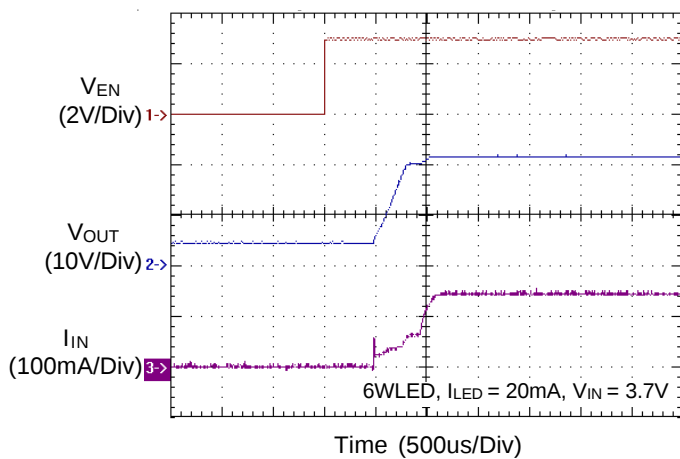
OVP Voltage vs. Input Voltage



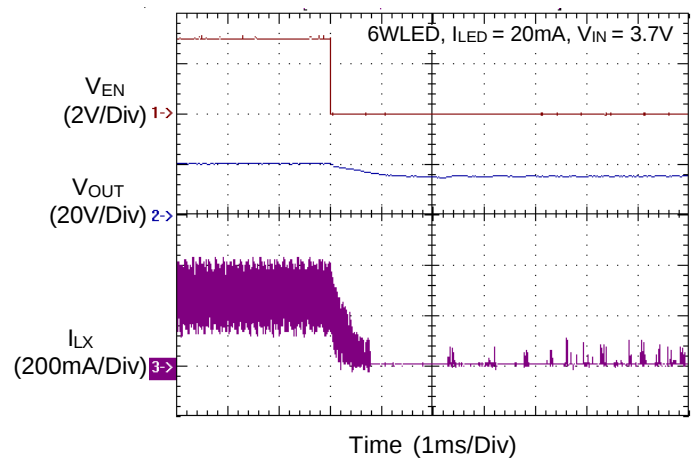
LED Current vs. Duty



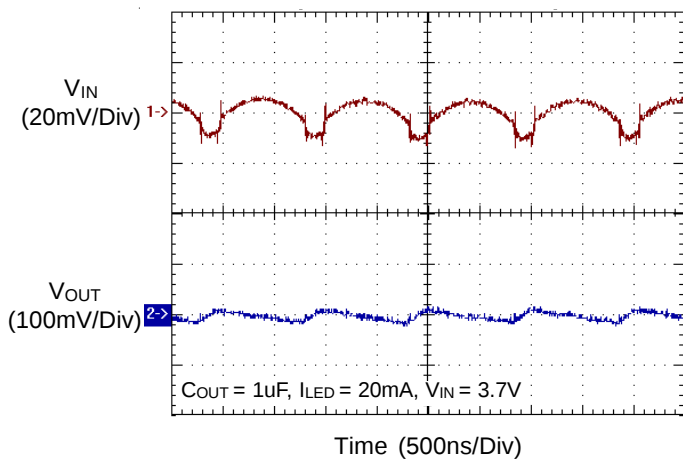
Power On from EN



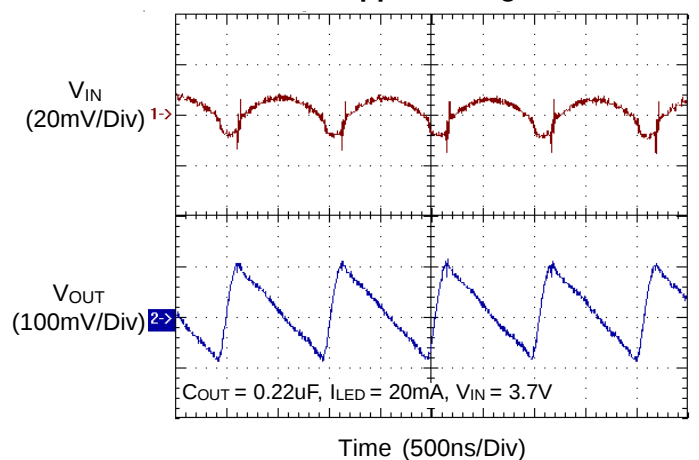
Power Off from EN



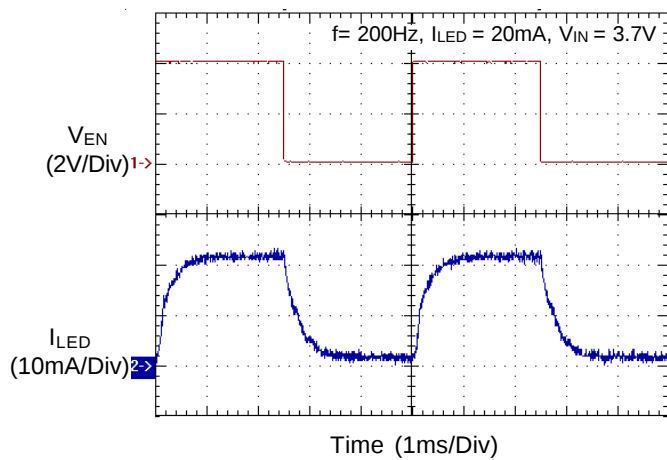
Ripple Voltage



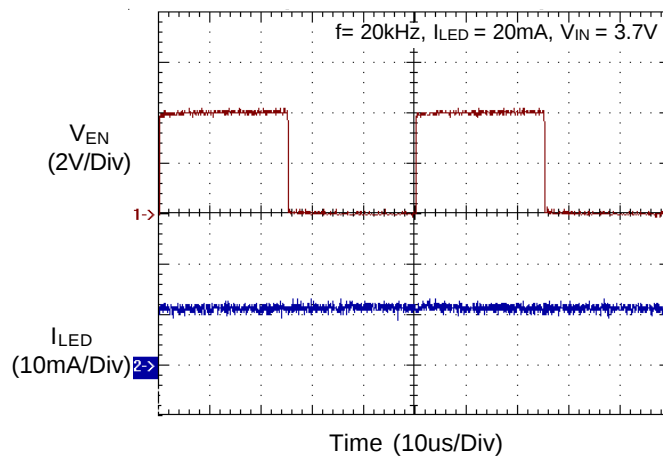
Ripple Voltage



PWM Dimming from EN



PWM Dimming from EN



Applications Information

LED Current Setting

The loop of Boost structure will keep the FB pin voltage equal to the reference voltage V_{REF} . Therefore, when R_{SET} connects FB pin and GND, the current flows from V_{OUT} through LED and R_{SET} to GND will be decided by the current on R_{SET} , which is equal to following Equation :

$$I_{LED} = \frac{V_{REF}}{R_{SET}}$$

Dimming Control

a. Using a PWM Signal to EN Pin

For the brightness dimming control of the RT9292, the IC provides typically 330mV feedback voltage when the EN pin is pulled constantly high. However, EN pin allows a PWM signal to reduce this regulation voltage by changing the PWM duty cycle to achieve LED brightness dimming control. The relationship between the duty cycle and FB voltage can be calculated as following equation.

$$V_{FB} = \text{Duty} \times 330\text{mV}$$

Where

Duty = duty cycle of the PWM signal

330mV = internal reference voltage

As shown in Figure 1, the duty cycle of the PWM signal is used to cut the internal 330mV reference voltage. An internal low pass filter is used to filter the pulse signal. And then the reference voltage can be made by connecting the output of the filter to the error amplifier for the FB pin voltage regulation.

However, the internal low pass filter 3db frequency is 500Hz. When the dimming frequency is lower than 500Hz, V_A is also a PWM signal and the LED current is controlled directly by this signal. When the frequency is higher than 500Hz, PWM is filtered by the internal low pass filter and the V_A approach a DC signal. And the LED current is a DC current which eliminate the audio noise. Two figures of PWM Dimming from EN are shown in Typical Operating Characteristics section and the PWM dimming frequency is 200Hz and 20kHz respectively.

But there is an offset in error amplifier which will cause the V_A variation. In low PWM duty signal situation, the

filtered reference voltage is low and the offset can cause bigger variation of the output current. So RT9292B is not recommend to be dimming by EN pin. For RT9292D the minimum duty vs frequency is list in following table.

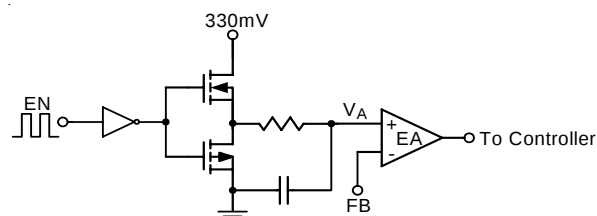


Figure 1. Block Diagram of Programmable FB Voltage Using PWM Signal

	Duty Minimum
Dimming frequency < 500Hz	4%
Dimming frequency > 500Hz	12%

b. Using a DC Voltage

Using a variable DC voltage to adjust the brightness is a popular method in some applications. The dimming control using a DC voltage circuit is shown in Figure 2. As the DC voltage increases, the current pass through R3 increasingly and the voltage drop on R3 increase, i.e. the LED current decreases. For example, if the V_{DC} range is from 0V to 2.8V and assume the RT9292 is selected which V_{REF} is equal to 0.33V, the selection of resistors in Figure 2 sets the LED current from 20.55mA to 0mA. The LED current can be calculated by the following Equation :

$$I_{LED} = \frac{V_{REF} - \frac{R3 \times (V_{DC} - V_{REF})}{R4}}{R_{SET}}$$

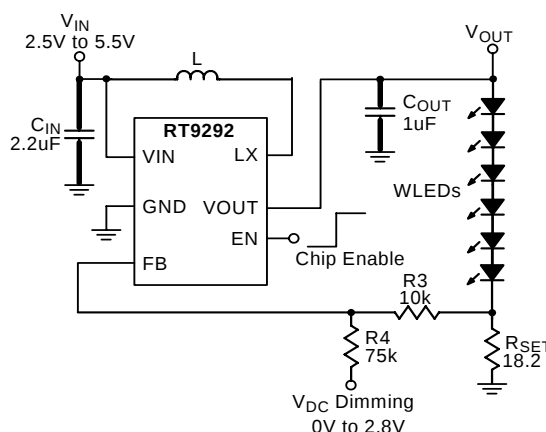


Figure 2. Dimming Control Using a DC Voltage for the RT9292

c. Using a Filtered PWM signal

Another common application is using a filtered PWM signal as an adjustable DC voltage for LED dimming control.

A filtered PWM signal acts as the DC voltage to regulate the output current. The recommended application circuit is shown as Figure 3. In this circuit, the output ripple depends on the frequency of PWM signal. For smaller output voltage ripple (<100mV), the recommended frequency of 2.8V PWM signal should be above 2kHz. To fix the frequency of PWM signal and change the duty cycle of PWM signal can get different output current. The LED current can be calculated by the following Equation :

$$I_{LED} = \frac{V_{REF} - \frac{R_3 \times (V_{PWM} \times \text{Duty} - V_{REF})}{R_4 + R_{DC}}}{R_{SET}}$$

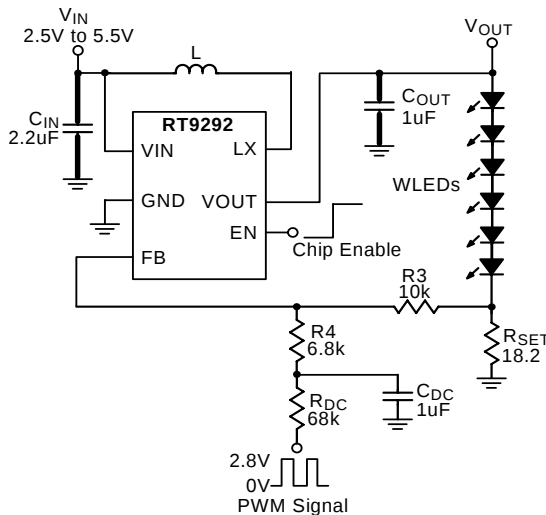


Figure 3. Filtered PWM Signal for LED Dimming Control of the RT9292

By the above equation and the application circuit shown in Figure 3, and assume the RT9292D is selected which V_{REF} is equal to 0.33V. Figure 4 shows the relationship between the LED current and PWM duty cycle. For example, when the PWM duty is equal to 60%, the LED current will be equal to 8.2mA. When the PWM duty is equal to 40%, the LED current will be equal to 12.3mA.

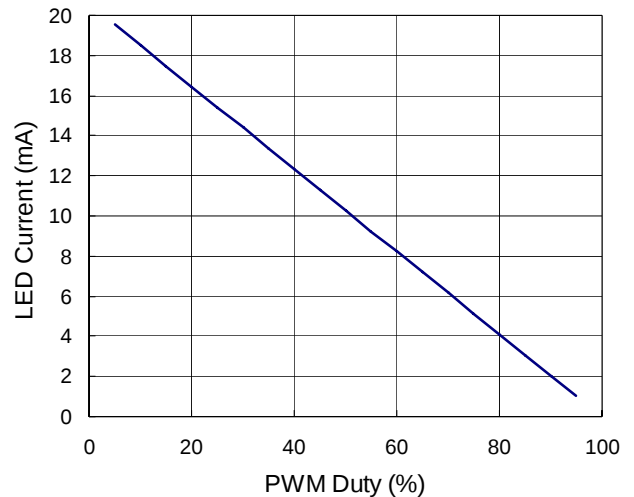


Figure 4. LED Current Variation with the PWM Dimming on FB

Constant Output Voltage Control

The output voltage of RT9292 can be adjusted by the divider circuit on FB pin. Figure 5 shows the application circuit for the constant output voltage. The output voltage can be calculated by the following Equations :

$$V_{OUT} = V_{REF} \times \frac{R_1 + R_2}{R_2}; R_2 > 10k$$

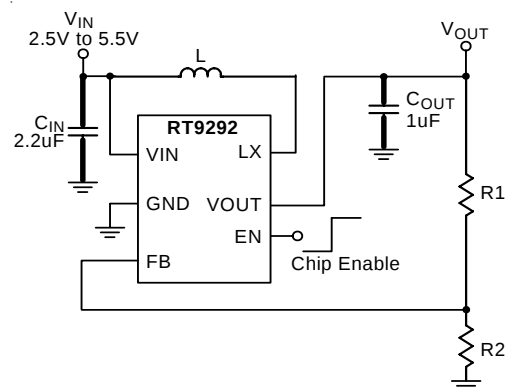


Figure 5. Application for Constant Output Voltage

Soft-Start

The function of soft-start is made for suppressing the inrush current to an acceptable value at the beginning of power-on. The soft-start function is built-in the RT9292 by clamping the output voltage of error amplifier so that the duty cycle of the PWM will be increased gradually in the soft-start period.

Current Limiting

The current flow through inductor as charging period is detected by a current sensing circuit. As the value comes across the current limiting threshold, the N-MOSFET will be turned off so that the inductor will be forced to leave charging stage and enter discharging stage. Therefore, the inductor current will not increase over the current limiting threshold.

OVP/UVLO/OTP

The Over Voltage Protection is detected by a junction breakdown detecting circuit. Once V_{OUT} goes over the detecting voltage, LX pin stops switching and the power N-MOSFET will be turned off. Then, the V_{OUT} will be clamped to be near V_{OVP} . As the output voltage is higher than a specified value or input voltage is lower than a specified value, the chip will enter protection mode to prevent abnormal function. As the die temperature $> 160^{\circ}\text{C}$, the chip also will enter protection mode. The power MOSFET will be turned off during protection mode to prevent abnormal operation.

Inductor Selection

The recommended value of inductor for 6 WLEDs applications is from 10uH to 33uH. Small size and better efficiency are the major concerns for portable devices, such as the RT9292 used for mobile phone. The inductor should have low core loss at 1MHz and low DCR for better efficiency. The inductor saturation current rating should be considered to cover the inductor peak current.

Capacitor Selection

Input ceramic capacitor of 2.2uF and output ceramic capacitor of 1uF are recommended for the RT9292 applications for driving 6 series WLEDs. For better voltage filtering, ceramic capacitors with low ESR are recommended. X5R and X7R types are suitable because of their wider voltage and temperature ranges.

Thermal Considerations

For continuous operation, do not exceed absolute maximum operation junction temperature. The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow

and temperature difference between junction to ambient. The maximum power dissipation can be calculated by following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

Where $T_{J(MAX)}$ is the maximum operation junction temperature, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance.

For recommended operating conditions specification of RT9292, the maximum junction temperature of the die is 125°C . The junction to ambient thermal resistance θ_{JA} is layout dependent. The junction to ambient thermal resistance for TSOT-23-6 package is 255°C/W and WDFN-8L 2x2 package is 165°C/W on the standard JEDEC 51-3 single-layer thermal test board. The maximum power dissipation at $T_A = 25^{\circ}\text{C}$ can be calculated by following formula :

$$P_{D(MAX)} = (125^{\circ}\text{C} - 25^{\circ}\text{C}) / (165^{\circ}\text{C/W}) = 0.606\text{W for WDFN-8L 2x2 packages}$$

$$P_{D(MAX)} = (125^{\circ}\text{C} - 25^{\circ}\text{C}) / (255^{\circ}\text{C/W}) = 0.392\text{W for TSOT-23-6 packages}$$

The maximum power dissipation depends on operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance θ_{JA} . For RT9292 packages, the Figure 6 of derating curves allows the designer to see the effect of rising ambient temperature on the maximum power allowed.

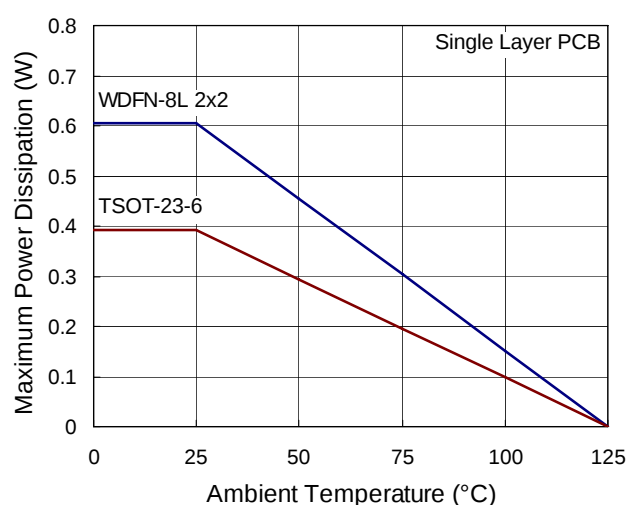


Figure 6. Derating Curves for RT9292 Packages

Layout Consideration

For best performance of the RT9292, the following guidelines must be strictly followed.

- ▶ Input and Output capacitors should be placed close to the IC and connected to ground plane to reduce noise coupling.
- ▶ The GND and Exposed Pad should be connected to a strong ground plane for heat sinking and noise protection.
- ▶ Keep the main current traces as possible as short and wide.
- ▶ LX node of DC-DC converter is with high frequency voltage swing. It should be kept at a small area.
- ▶ Place the feedback components as close as possible to the IC and keep away from the noisy devices.

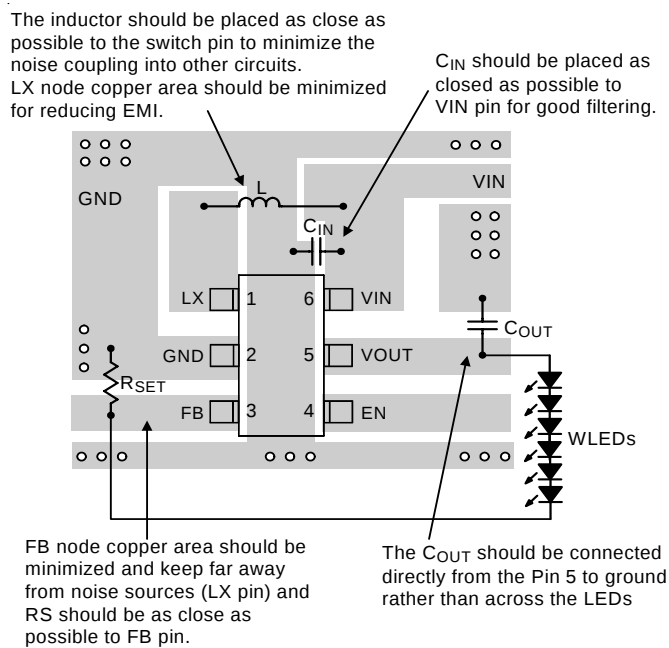
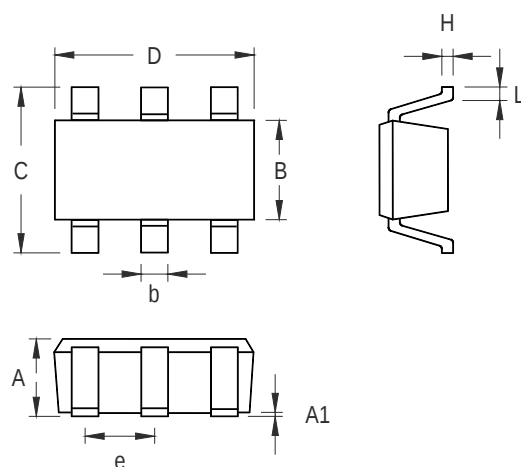


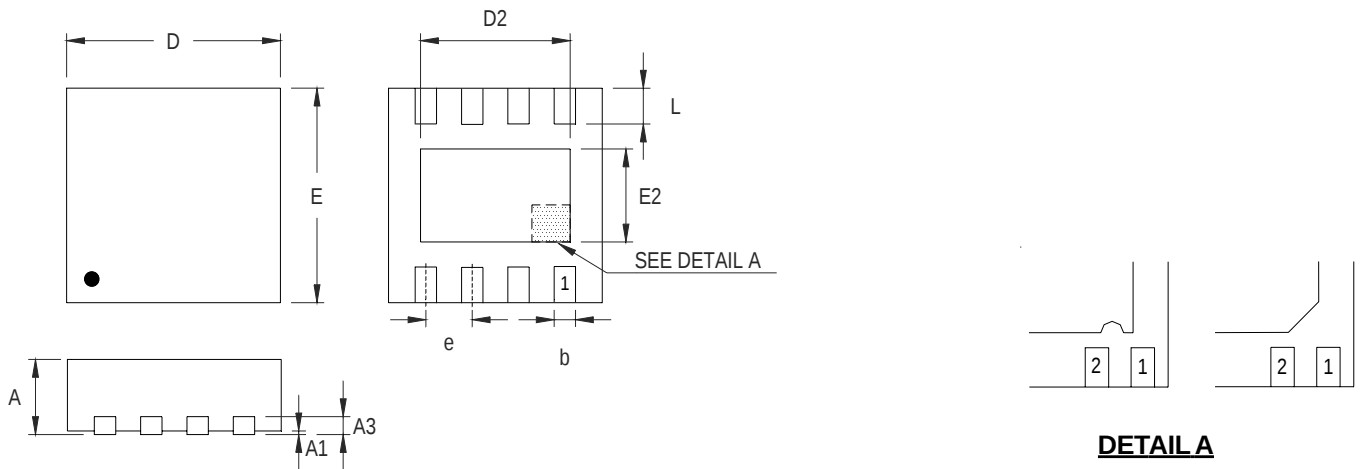
Figure 7. Layout Consideration Recommended

Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	1.000	0.028	0.039
A1	0.000	0.100	0.000	0.004
B	1.397	1.803	0.055	0.071
b	0.300	0.559	0.012	0.022
C	2.591	3.000	0.102	0.118
D	2.692	3.099	0.106	0.122
e	0.838	1.041	0.033	0.041
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

TSOT-23-6 Surface Mount Package



Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.200	0.300	0.008	0.012
D	1.950	2.050	0.077	0.081
D2	1.000	1.250	0.039	0.049
E	1.950	2.050	0.077	0.081
E2	0.400	0.650	0.016	0.026
e	0.500		0.020	
L	0.300	0.400	0.012	0.016

W-Type 8L DFN 2x2 Package

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